

## 24NM70

Power MOSFET

24A, 700V N-CHANNEL  
SUPER-JUNCTION MOSFET

## ■ DESCRIPTION

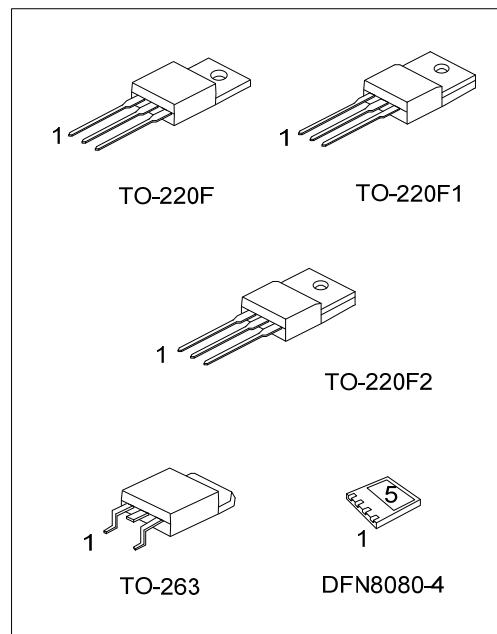
The **UTC 24NM70** is a Super Junction MOSFET Structure and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and a high rugged avalanche characteristics. This power MOSFET is usually used at AC-DC converters for power applications.

## ■ FEATURES

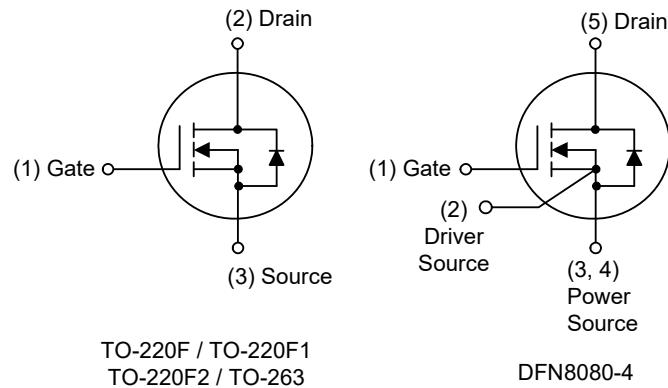
\*  $R_{DS(ON)} \leq 0.19 \Omega$  @  $V_{GS}=10V$ ,  $I_D=12A$ 

\* High Switching Speed

\* 100% Avalanche Tested



## ■ SYMBOL



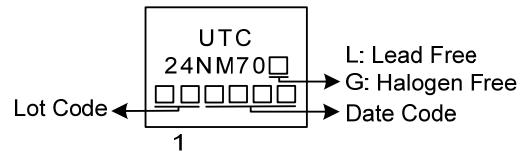
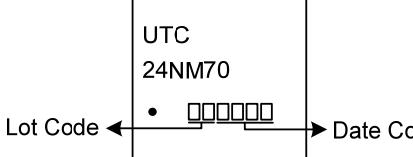
## ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment					Packing
Lead Free	Halogen Free		1	2	3	4	5	
24NM70L-TF1-T	24NM70G-TF1-T	TO-220F1	G	D	S	-	-	Tube
24NM70L-TF2-T	24NM70G-TF2-T	TO-220F2	G	D	S	-	-	Tube
24NM70L-TF3-T	24NM70G-TF3-T	TO-220F	G	D	S	-	-	Tube
24NM70L-TQ2-T	24NM70G-TQ2-T	TO-263	G	D	S	-	-	Tube
24NM70L-TQ2-R	24NM70G-TQ2-R	TO-263	G	D	S	-	-	Tape Reel
24NM70L-K04-8080-R	24NM70G-K04-8080-R	DFN8080-4	G	S	S	S	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

 (1)Packing Type (2)Package Type (3)Green Package	(1) T: Tube, R:Tape Reel (2) TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F TQ2: TO-263, K04-8080: DFN8080-4 (3) G: Halogen Free and Lead Free, L: Lead Free				

**■ MARKING**

TO-220F / TO-220F1 / TO-220F2 / TO-263	DFN8080-4
	

■ ABSOLUTE MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER			SYMBOL	RATINGS	UNIT
Drain-Source Voltage			$V_{DSS}$	700	V
Gate-Source Voltage			$V_{GSS}$	$\pm 30$	V
Drain Current	Continuous	$T_c=25^\circ\text{C}$	$I_D$	24	A
		$T_c=100^\circ\text{C}$		14.4	A
	Pulsed (Note 2)		$I_{DM}$	72	A
Avalanche Current (Note 2)			$I_{AR}$	5.2	A
Avalanche Energy	Single Pulsed (Note 3)		$E_{AS}$	879	mJ
Peak Diode Recovery $dv/dt$			$dv/dt$	6.3	V/ns
Power Dissipation	TO-220F/TO-220F1		$P_D$	36	W
	TO-220F2			127	W
	TO-263			68	W
	DFN8080-4				
Junction Temperature			$T_J$	+150	$^\circ\text{C}$
Storage Temperature			$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3.  $L = 65\text{mH}$ ,  $I_{AS} = 5.2\text{A}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

4.  $I_{SD} \leq 24\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220F/TO-220F1	$\theta_{JA}$	62.5	$^\circ\text{C/W}$
	TO-220F2/TO-263		35 (Note)	$^\circ\text{C/W}$
	DFN8080-4			
Junction to Case	TO-220F/TO-220F1	$\theta_{JC}$	3.47	$^\circ\text{C/W}$
	TO-220F2		0.98 (Note)	$^\circ\text{C/W}$
	TO-263		1.83 (Note)	$^\circ\text{C/W}$
	DFN8080-4			

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

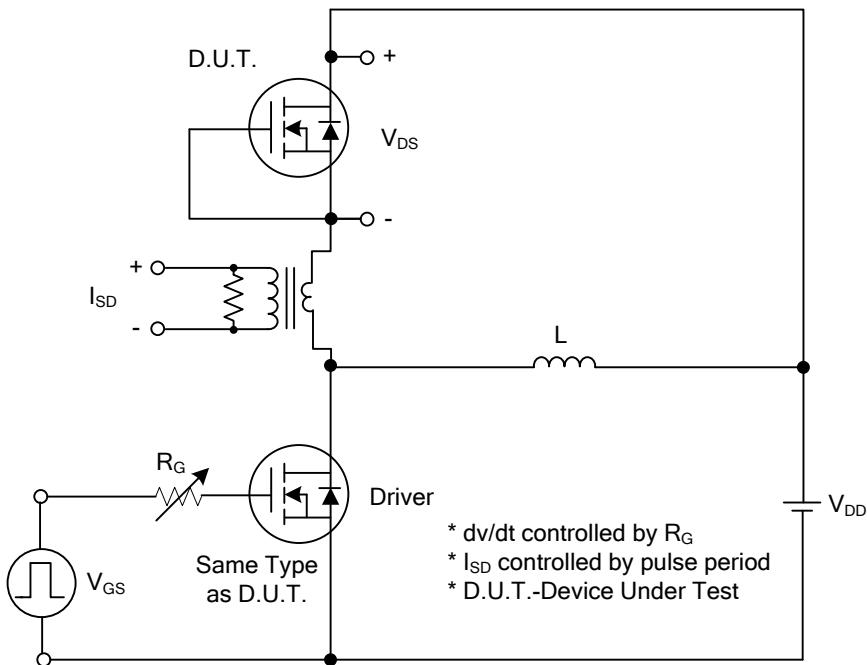
■ ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	700			V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{DS}=700\text{V}, V_{GS}=0\text{V}$		10		$\mu\text{A}$
Gate- Source Leakage Current	Forward	$I_{\text{GSS}}$	$V_{GS}=+30\text{V}, V_{DS}=0\text{V}$		+100	nA
	Reverse		$V_{GS}=-30\text{V}, V_{DS}=0\text{V}$		-100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2.5		4.5	V
Static Drain-Source On-State Resistance	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=12\text{A}$		0.18	0.19	$\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{\text{ISS}}$	$V_{GS}=0\text{V}, V_{DS}=50\text{V}, f=1.0\text{MHz}$		1920		pF
Output Capacitance	$C_{\text{OSS}}$			250		pF
Reverse Transfer Capacitance	$C_{\text{RSS}}$			10		pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge (Note 1)	$Q_G$	$V_{DS}=560\text{V}, V_{GS}=10\text{V}, I_D=24\text{A}$ (Note1, 2)		70		nC
Gate to Source Charge	$Q_{GS}$			9.6		nC
Gate to Drain Charge	$Q_{GD}$			27.2		nC
Turn-ON Delay Time (Note 1)	$t_{D(\text{ON})}$	$V_{DS}=100\text{V}, V_{GS}=10\text{V}, I_D=24\text{A},$ $R_G=25\Omega$ (Note1, 2)		26		ns
Rise Time	$t_R$			32		ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			240		ns
Fall-Time	$t_F$			110		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Body-Diode Continuous Current	$I_S$				24	A
Maximum Body-Diode Pulsed Current	$I_{SM}$				96	A
Drain-Source Diode Forward Voltage (Note 1)	$V_{SD}$	$I_S=24\text{A}, V_{GS}=0\text{V}$			1.4	V
Body Diode Reverse Recovery Time (Note 1)	$t_{rr}$	$I_S=24\text{A}, V_{GS}=0\text{V},$ $dI_F/dt=100\text{A}/\mu\text{s}$		520		ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			10.5		$\mu\text{C}$

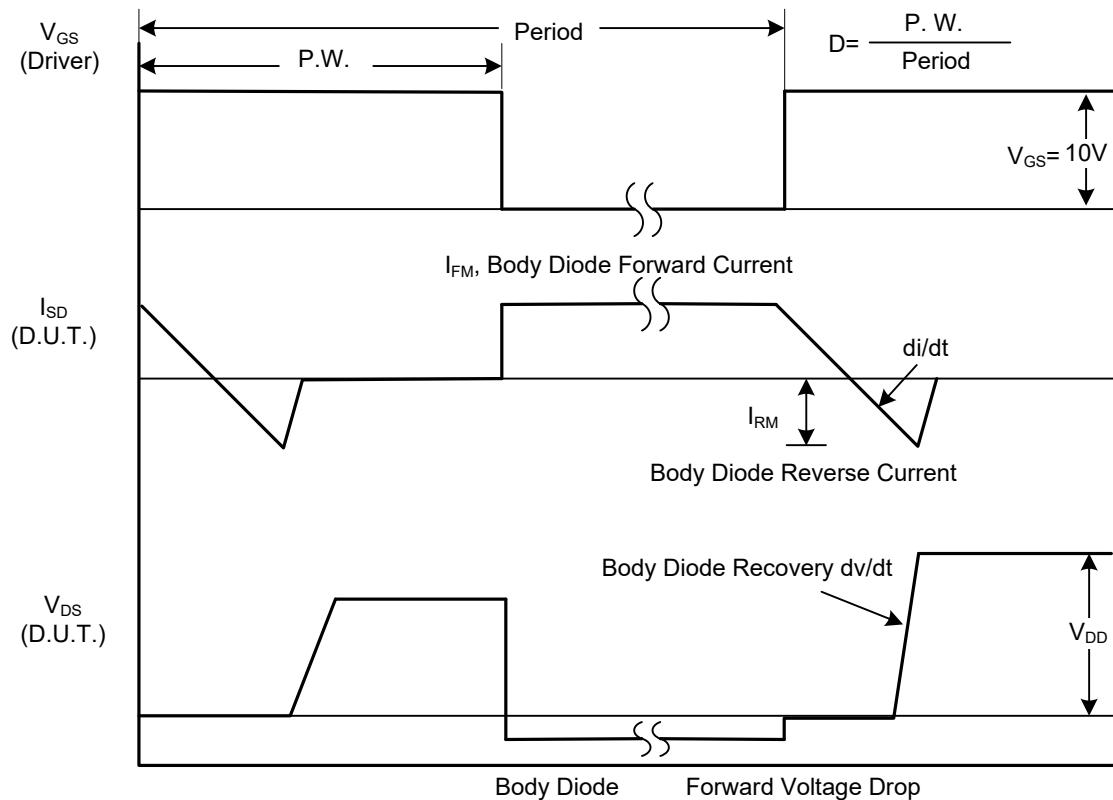
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating ambient temperature.

■ TEST CIRCUITS AND WAVEFORMS

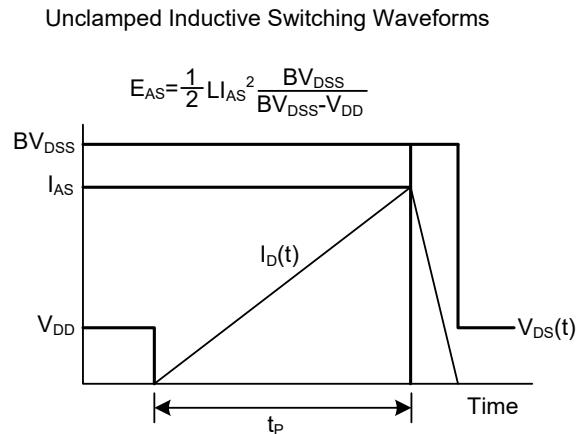
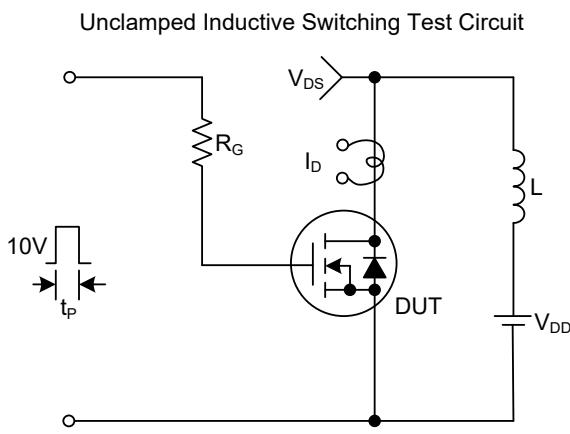
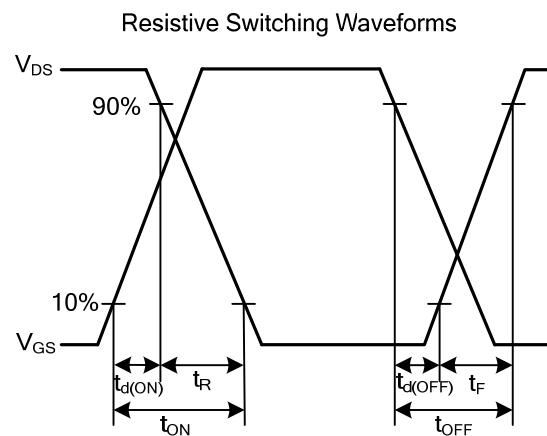
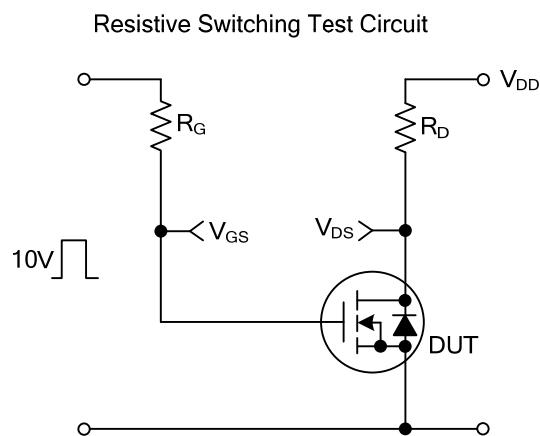
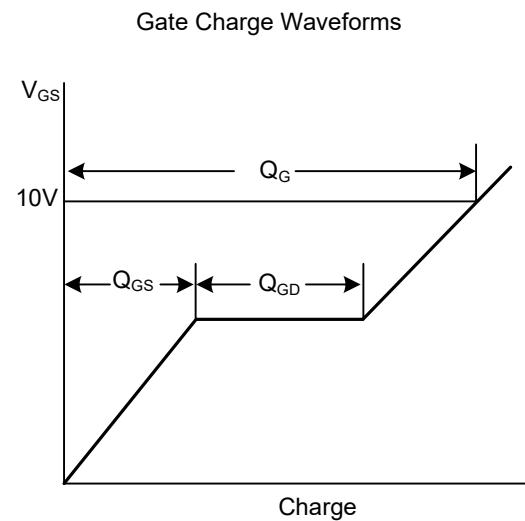
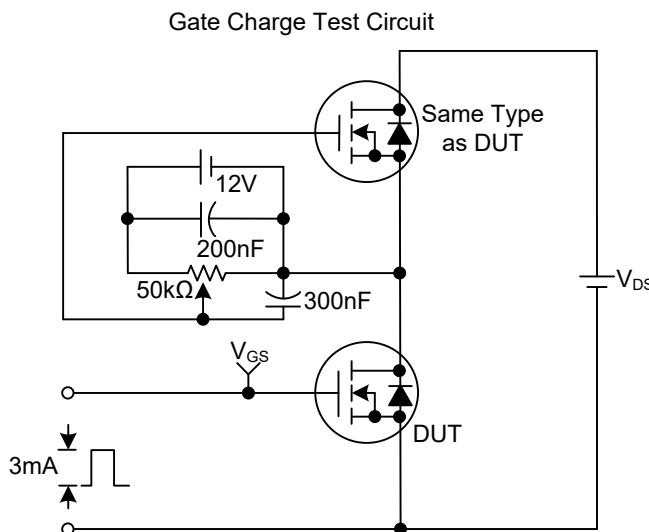


Peak Diode Recovery  $dv/dt$  Test Circuit

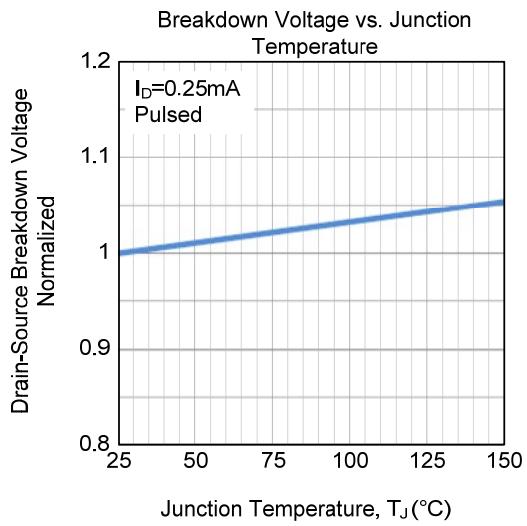
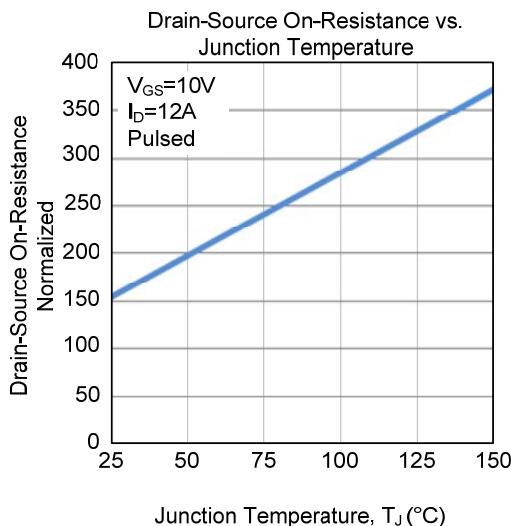
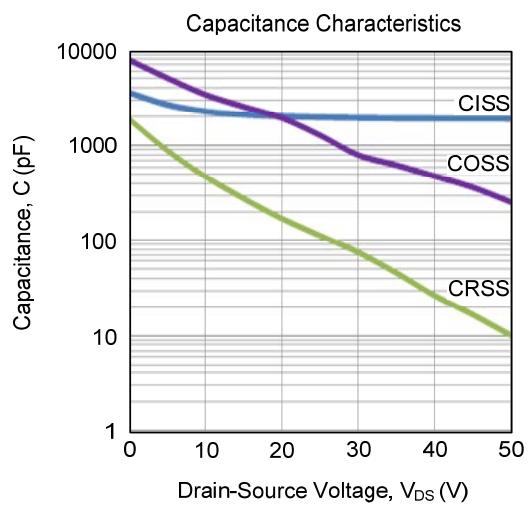
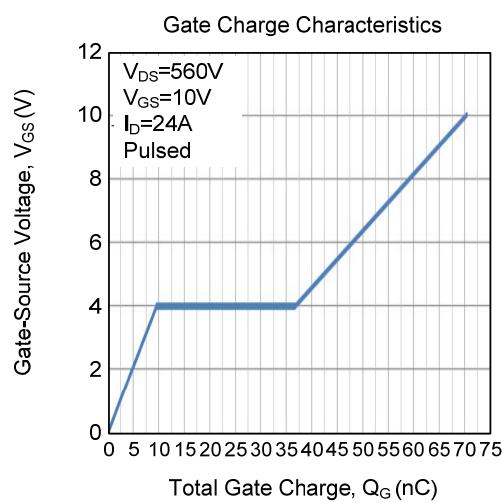
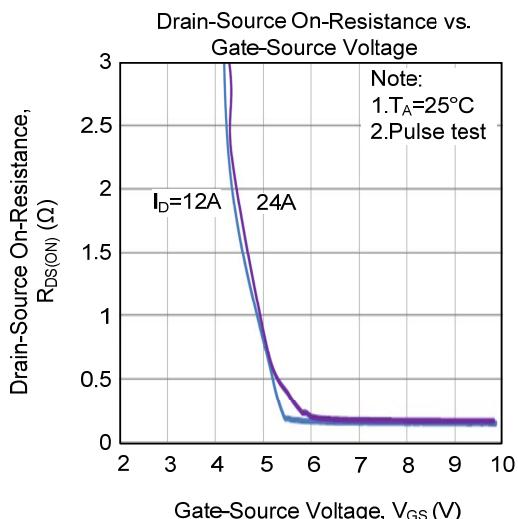
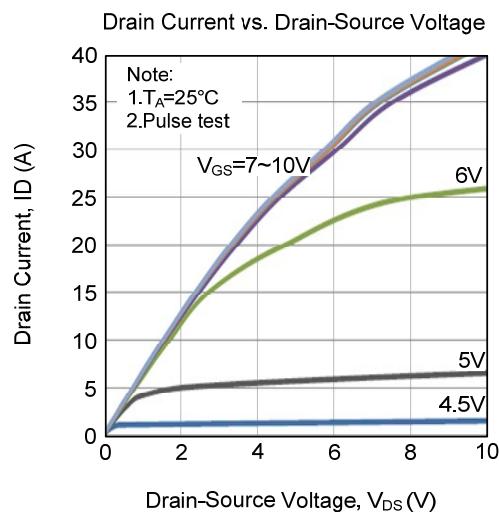


Peak Diode Recovery  $dv/dt$  Waveforms

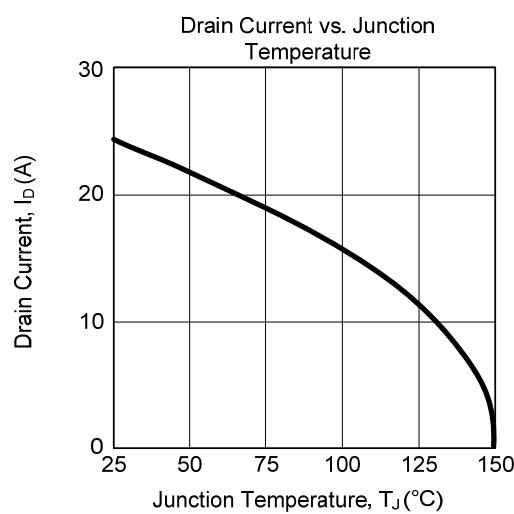
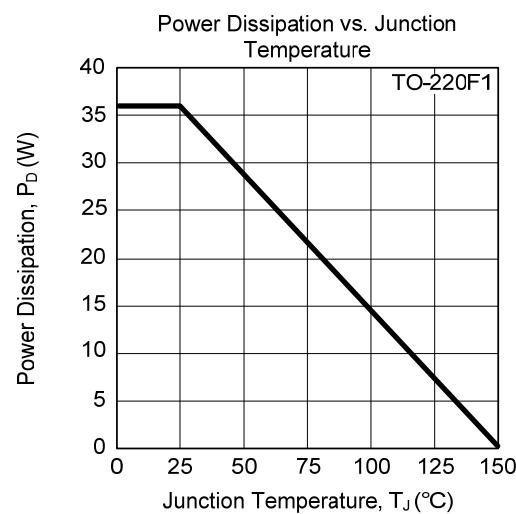
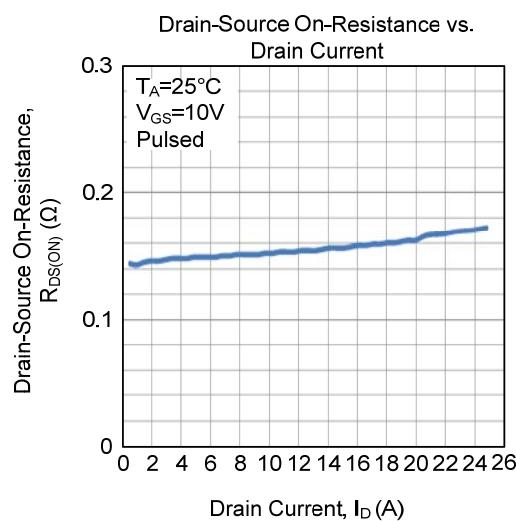
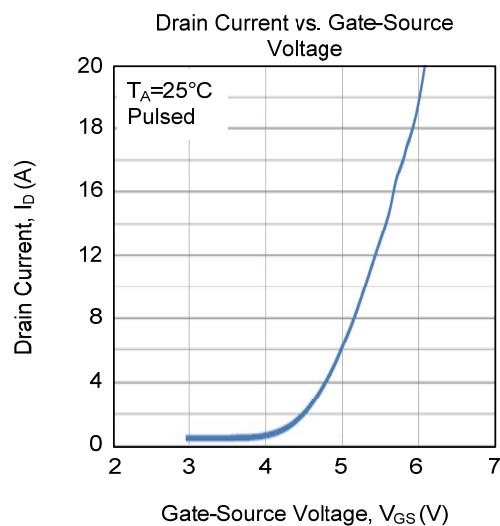
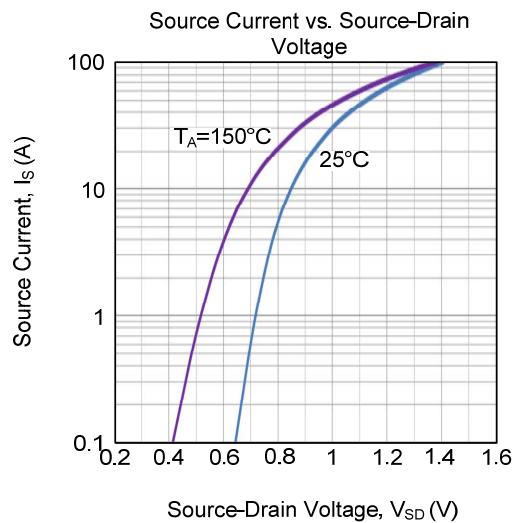
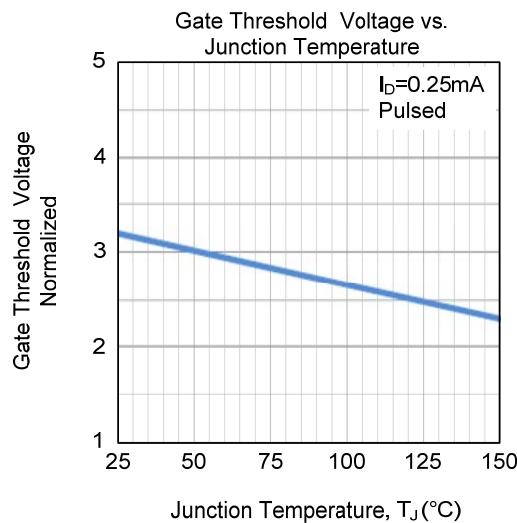
■ TEST CIRCUITS AND WAVEFORMS

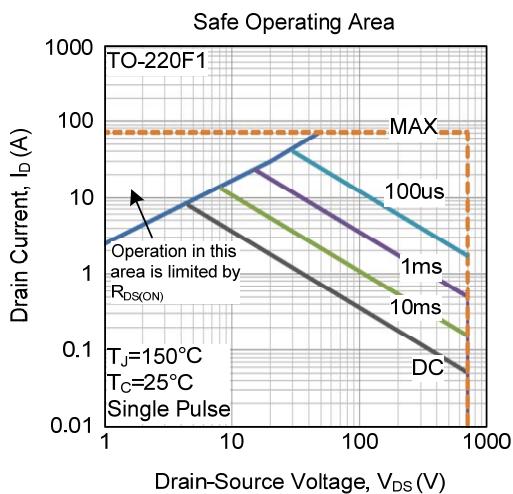


■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



**■ TYPICAL CHARACTERISTICS (Cont.)**

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